

2GB, 4GB, 8GB, 16GB, 32GB, 64GB: e-MMC

**Features** 

## e·MMC<sup>TM</sup> Memory

### MTFC2GMDEA-0M WT, MTFC4GLDEA-0M WT, MTFC4GMDEA-1M WT, MTFC8GLDEA-1M WT, MTFC16GJDEC-2M WT, MTFC32GJDED-3M WT, MTFC64GJDDN-3M WT

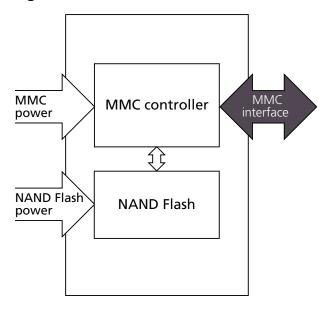
#### **Features**

- MultiMediaCard (MMC) controller and NAND Flash
- 153- or 169-ball WFBGA/VFBGA/LFBGA (RoHS 6/6compliant)
- V<sub>CC</sub>: 2.7-3.6V
- V<sub>CCO</sub> (dual voltage): 1.65–1.95V; 2.7–3.6V
- Temperature ranges
  - Operating temperature: -25°C to +85°C
  - Storage temperature: -40°C to +85°C
- Typical current consumption
  - Standby current: 110µA for 2GB, 120µA for 4GB, 8GB, 16GB; 140µA for 32G; 160µA for 64GB
  - Active current (RMS): 70mA (2GB); 80mA (4GB, 8GB, 16GB, 32GB, 64GB)

### **MMC-Specific Features**

- JEDEC/MMC standard version 4.41-compliant (IEDEC Standard No. 84-A441) – SPI mode not supported (see www.jedec.org/sites/default/files/ docs/JESD84-A441.pdf)
  - Advanced 11-signal interface
  - x1, x4, and x8 I/Os, selectable by host
  - MMC mode operation
  - Command classes: class 0 (basic); class 2 (block read); class 4 (block write); class 5 (erase): class 6 (write protection); class 7 (lock card)
  - MMC*plus*™ and MMC*mobile*™ protocols
  - Temporary write protection
  - 52 MHz clock speed (MAX)
  - Boot operation (high-speed boot)
  - Sleep mode
  - Replay-protected memory block (RPMB)
  - Secure erase and trim
  - Hardware reset signal
  - Multiple partitions with enhanced attribute
  - Permanent and power-on write protection
  - Double data rate (DDR) function
  - High-priority interrupt (HPI)

Figure 1: Micron e-MMC Device



#### **MMC-Specific Features (Continued)**

- Enhanced reliable write
- Configurable reliability settings
- Background operation
- Fully enhanced configurable
- Backward-compatible with previous MMC modes
- ECC and block management implemented



### 2GB, 4GB, 8GB, 16GB, 32GB, 64GB: e·MMC Features

#### e-MMC Performance

**Table 1: MLC Partition Performance** 

|                  | Part Number                          |                                      |   |       |  |  |  |  |
|------------------|--------------------------------------|--------------------------------------|---|-------|--|--|--|--|
| Condition        | MTFC2GMDEA-0M WT<br>MTFC4GLDEA-0M WT | MTFC4GMDEA-1M WT<br>MTFC8GLDEA-1M WT | MTFC16GJDEC-2M WT<br>MTFC32GJDED-3M WT<br>MTFC64GJDDN-3M WT | Units |  |  |  |  |
| Sequential write | 6.6                                  | 13.5                                 | 20  | MB/s  |  |  |  |  |
| Sequential read  | 30                                   | 44                                   | 44  | MB/s  |  |  |  |  |
| Random write     | 90                                   | 90                                   | 90  | IOPs  |  |  |  |  |
| Random read      | 1080                                 | 1080                                 | 1100  | IOPs  |  |  |  |  |

Note: 1. Bus in x8 I/O mode. Sequential access of 1MB chunk; random access of 4KB chunk. Additional performance data, such as power consumption or timing for different device modes, will be provided in a separate document upon customer request.

### **Ordering Information**

**Table 2: Ordering Information** 

| Base Part Number  | Density | Package                 | NAND Flash<br>Type  | Shipping Media |
|-------------------|---------|-------------------------|---------------------|----------------|
| MTFC2GMDEA-0M WT  | 2GB     | 153-ball WFBGA          | 1 x 16Gb, MLC, 25nm | Tray           |
|                   |         | 11.5mm x 13.0mm x 0.8mm |                     | Tape and reel  |
| MTFC4GLDEA-0M WT  | 4GB     | 153-ball WFBGA          | 1 x 32Gb, MLC, 25nm | Tray           |
|                   |         | 11.5mm x 13.0mm x 0.8mm |                     | Tape and reel  |
| MTFC4GMDEA-1M WT  | 4GB     | 153-ball WFBGA          | 2 x 16Gb, MLC, 25nm | Tray           |
|                   |         | 11.5mm x 13.0mm x 0.8mm |                     | Tape and reel  |
| MTFC8GLDEA-1M WT  | 8GB     | 153-ball WFBGA          | 2 x 32Gb, MLC, 25nm | Tray           |
|                   |         | 11.5mm x 13.0mm x 0.8mm |                     | Tape and reel  |
| MTFC16GJDEC-2M WT | 16GB    | 169-ball WFBGA          | 2 x 64Gb, MLC, 25nm | Tray           |
|                   |         | 14.0mm x 18.0mm x 0.8mm |                     | Tape and reel  |
| MTFC32GJDED-3M WT | 32GB    | 169-ball VFBGA          | 4 x 64Gb, MLC, 25nm | Tray           |
|                   |         | 14.0mm x 18.0mm x 1.0mm |                     | Tape and reel  |
| MTFC64GJDDN-3M WT | 64GB    | 169-ball LFBGA          | 8 x 64Gb, MLC, 25nm | Tray           |
|                   |         | 14.0mm x 18.0mm x 1.4mm |                     | Tape and reel  |

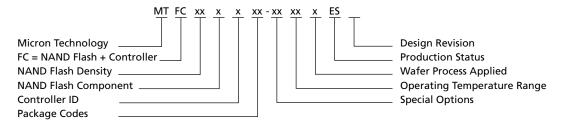


2GB, 4GB, 8GB, 16GB, 32GB, 64GB: e·MMC Features

### **Part Numbering Information**

Micron<sup>®</sup> *e*·MMC memory devices are available in different configurations and densities. Verify valid part numbers by using Micron's part catalog search at www.micron.com. To compare features and specifications by device type, visit www.micron.com/products. Contact the factory for devices not found.

**Figure 2: Marketing Part Number Chart** 



Note: 1. Not all combinations are necessarily available. For a list of available devices or for further information on any aspect of these products, please contact your nearest Micron sales office.

### **Device Marking**

Due to the size of the package, the Micron-standard part number is not printed on the top of the device. Instead, an abbreviated device mark consisting of a 5-digit alphanumeric code is used. The abbreviated device marks are cross-referenced to the Micron part numbers at the FBGA Part Marking Decoder site: www.micron.com/decoder.



## 2GB, 4GB, 8GB, 16GB, 32GB, 64GB: e·MMC General Description

## **General Description**

Micron *e*·MMC is a communication and mass data storage device that includes a Multi-MediaCard (MMC) interface, a NAND Flash component, and a controller on an advanced 11-signal bus, which is compliant with the MMC system specification. Its low cost, small size, Flash technology independence, and high data throughput make *e*·MMC ideal for embedded applications like set-top boxes, digital cameras/camcorders, digital TVs, and a variety other consumer products.

The nonvolatile e·MMC draws no power to maintain stored data, delivers high performance across a wide range of operating temperatures, and resists shock and vibration disruption.



# 2GB, 4GB, 8GB, 16GB, 32GB, 64GB: e·MMC Signal Descriptions

## **Signal Descriptions**

**Table 3: Signal Descriptions** 

| Symbol                        | Туре   | Description  |
|-------------------------------|--------|--|
| CLK                           | Input  | Clock: Each cycle of the clock directs a transfer on the command line and on the data line(s). The frequency can vary between the minimum and the maximum clock frequency.   |
| RST_n                         | Input  | Reset: The RST_n signal is used by the host for resetting the device, moving the device to the pre-<br>idle state. By default, the RST_n signal is temporarily disabled in the device. The host must set ECSD<br>register byte 162, bits[1:0] to 0x1 to enable this functionality before the host can use it.  |
| CMD                           | I/O    | Command: This signal is a bidirectional command channel used for command and response transfers. The CMD signal has two bus modes: open-drain mode and push-pull mode (see Operating Modes). Commands are sent from the MMC host to the device, and responses are sent from the device to the host.  |
| DAT[7:0]                      | I/O    | Data I/O: These are bidirectional data signals. The DAT signals operate in push-pull mode. By default, after power-on or assertion of the RST_n signal, only DAT0 is used for data transfer. The MMC controller can configure a wider data bus for data transfer either using DAT[3:0] (4-bit mode) or DAT[7:0] (8-bit mode). e·MMC includes internal pull-up resistors for data lines DAT[7:1]. Immediately after entering the 4-bit mode, the device disconnects the internal pull-up resistors on the DAT[3:1] lines. Upon entering the 8-bit mode, the device disconnects the internal pull-ups on the DAT[7:1] lines. |
| V <sub>CC</sub>               | Supply | V <sub>CC</sub> : NAND interface (I/F) I/O and NAND Flash power supply.  |
| $V_{CCQ}$                     | Supply | V <sub>CCQ</sub> : e·MMC controller core and e·MMC I/F I/O power supply.   |
| V <sub>SS</sub> <sup>1</sup>  | Supply | V <sub>SS</sub> : NAND I/F I/O and NAND Flash ground connection.   |
| V <sub>SSQ</sub> <sup>1</sup> | Supply | V <sub>SSQ</sub> : e·MMC controller core and e·MMC I/F ground connection.  |
| V <sub>DDIM</sub>             |        | Internal voltage node: At least a $0.1\mu F$ capacitor is required to connect $V_{DDIM}$ to ground. A $1\mu F$ capacitor is recommended. Do not tie to supply voltage or ground.   |
| NC                            | _      | No connect: No internal connection is present.   |
| RFU                           | _      | Reserved for future use: No internal connection is present. Leave it floating externally.  |

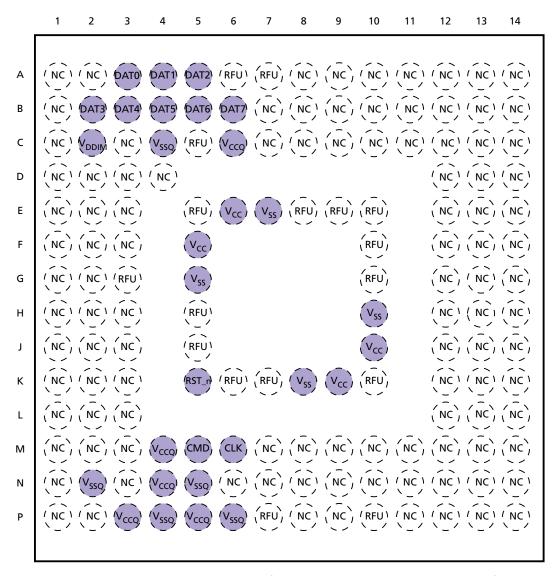
Note: 1.  $V_{SS}$  and  $V_{SSQ}$  are connected internally.



### 2GB, 4GB, 8GB, 16GB, 32GB, 64GB: e·MMC 153-Ball Signal Assignments

### **153-Ball Signal Assignments**

Figure 3: 153-Ball FBGA (Top View, Ball Down)



Notes: 1. Some previous versions of the JEDEC product or mechanical specification had defined reserved for future use (RFU) balls as no connect (NC) balls. NC balls assigned in the previous specifications could have been connected to ground on the system board. To enable new feature introduction, some of these balls are assigned as RFU in the v4.4 mechanical specification. Any new PCB footprint implementations should use the new ball assignments and leave the RFU balls floating on the system board.

2.  $V_{CC}$ ,  $V_{CCQ}$ ,  $V_{SS}$ , and  $V_{SSQ}$  balls must all be connected.



## 2GB, 4GB, 8GB, 16GB, 32GB, 64GB: e·MMC 169-Ball Signal Assignments

## **169-Ball Signal Assignments**

### Figure 4: 169-Ball FBGA (Top View, Ball Down)

|    | 1    | 2                   | 3                   | 4                     | 5                     | 6                     | 7                     | 8                     | 9                      | 10         | 11             | 12   | 13   | 14         |
|----|------|---------------------|---------------------|-----------------------|-----------------------|-----------------------|-----------------------|-----------------------|------------------------|------------|----------------|------|------|------------|
| А  |      |                     |                     | (NC)                  |                       | (NC)                  |                       |                       | (NC)                   |            | (NC)           |      |      |            |
| В  |      | (NC)                |                     | Ō                     |                       | Ō                     |                       |                       | $(\tilde{\mathbb{O}})$ |            | Ō              |      | (NC) |            |
| С  |      | $\bigcirc$          |                     |                       |                       | $\bigcirc$            |                       |                       | $\bigcirc$             |            | $\bigcirc$     |      | ()   |            |
| D  | (NC) | $\bigcirc$          |                     | ()                    |                       | $\bigcirc$            |                       |                       | $\bigcirc$             |            | ()             |      | ()   | (NC)       |
| Ε  |      | $\bigcirc$          |                     | ()                    |                       | $\bigcirc$            |                       |                       | $\bigcirc$             |            | ()             |      | ()   | $\bigcirc$ |
| F  |      | ()                  |                     | ()                    |                       | 0                     |                       |                       | ()                     |            | ()             |      | ()   |            |
| G  |      | 0                   |                     | ()                    |                       | ()                    |                       |                       | ()                     |            | ()             |      |      |            |
| Н  | (NC) | (NC)                | DATO)               | (DAT1)                | DAT2                  | (RFU)                 | (RFU)                 | (NC)                  | (NC)                   | (NC)       | (NC)           | (NC) | (NC) | (NC)       |
| J  | (NC) | (DAT3)              | DAT4                | (DAT5)                | DAT6                  | DAT7                  | (NC)                  | (NC)                  | (NC)                   | (NC)       | (NC)           | (NC) | (NC) | (NC)       |
| Κ  | (NC) | VDDIM               | (NC)                | (V <sub>SSQ</sub> )   | (RFU)                 | (V <sub>cco</sub> )   | (NC)                  | (NC)                  | (NC)                   | (NC)       | (NC)           | (NC) | (NC) | (NC)       |
| L  | (NC) | (NC)                | (NC)                | (NC)                  | _                     |                       |                       | _                     | _                      | _          |                | (NC) | (NC) | (NC)       |
| М  | (NC) | (NC)                | (NC)                |                       | (RFU)                 | $(v_{cc})$            | $\left(v_{ss}\right)$ | (RFU)                 | (RFU)                  | (RFU)      |                | (NC) | (NC) | (NC)       |
| N  | (NC) | (NC)                | (NC)                |                       | (v <sub>cc</sub> )    |                       |                       |                       |                        | (RFU)      |                | (NC) | (NC) | (NC)       |
| Р  | (NC) | (NC)                | (RFU)               |                       | $\left(v_{ss}\right)$ |                       |                       |                       |                        | (RFU)      |                | (NC) | (NC) | (NC)       |
| R  | (NC) | (NC)                | (NC)                |                       | (RFU)                 |                       |                       |                       |                        | $(v_{ss})$ |                | (NC) | (NC) | (NC)       |
| T  | (NC) | (NC)                | (NC)                |                       | (RFU),                |                       |                       |                       |                        | $(v_{cc})$ |                | (NC) | (NC) | (NC)       |
| U  | (NC) | (NC)                | (NC)                |                       | RST_n                 | (RFU)                 | (RFU),                | $\left(V_{SS}\right)$ | $(v_{cc})$             | (RFU),     |                | (NC) | (NC) | (NC)       |
| V  | (NC) | (NC)                | (NC)                |                       |                       |                       |                       | . – .                 | . – .                  | . – .      | . – .          | (NC) | (NC) | (NC)       |
| W  | (NC) | (NC)                | (NC)                | (V <sub>cco</sub> )   | (CMD)                 | (CLK)                 | (NC)                  | (NC)                  | (NC)                   | (NC)       | (NC)           | (NC) | (NC) | (NC)       |
| Υ  | (NC) | (V <sub>SSQ</sub> ) | (NC)                | (Acco)                | (V <sub>SSQ</sub> )   | (NC)                  | (NC)                  | (NC)                  | (NC)                   | (NC)       | (NC)           | (NC) | (NC) | ( NC )     |
| AA | (NC) | (NC)                | (A <sup>CCO</sup> ) | (V <sub>sso</sub> )   | (A <sup>CCO</sup> )   | (V <sub>sso</sub> )   | (RFU)                 | ( NC )                | (NC)                   | (RFU)      | (NC)           | (NC) | (NC) | (NC)       |
| AB |      |                     |                     |                       |                       | $(\underline{\zeta})$ |                       |                       |                        |            |                |      |      |            |
| AC |      |                     |                     |                       |                       | $(\underline{\zeta})$ |                       |                       |                        |            |                |      |      |            |
| AD |      |                     |                     | $(\underline{\zeta})$ |                       |                       |                       |                       |                        |            |                |      |      |            |
| AE | (NC) |                     |                     |                       |                       |                       |                       |                       |                        |            |                |      |      | (NC)       |
| AF |      |                     |                     |                       |                       |                       |                       |                       |                        |            | $\binom{1}{2}$ |      |      |            |
| AG |      | (NC)                |                     |                       |                       |                       |                       |                       |                        |            |                |      | (NC) |            |
| АН |      |                     |                     | (NC)                  |                       | (NC)                  |                       |                       | (NC)                   |            | (NC)           |      |      |            |

#### Micron Confidential and Proprietary



## 2GB, 4GB, 8GB, 16GB, 32GB, 64GB: e·MMC 169-Ball Signal Assignments

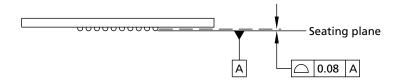
Notes:

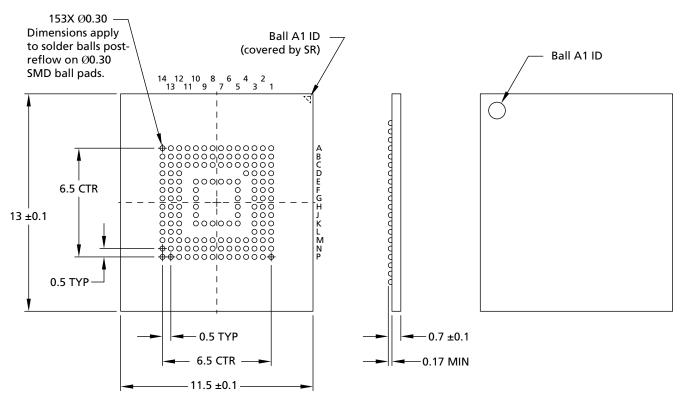
- 1. Empty balls do not denote actual solder balls; they are position indicators only.
- 2. Some previous versions of the JEDEC product or mechanical specification had defined reserved for future use (RFU) balls as no connect (NC) balls. NC balls assigned in the previous specifications could have been connected to ground on the system board. To enable new feature introduction, some of these balls are assigned as RFU in the v4.4 mechanical specification. Any new PCB footprint implementations should use the new ball assignments and leave the RFU balls floating on the system board.
- 3.  $V_{CC}$ ,  $V_{CCQ}$ ,  $V_{SS}$ , and  $V_{SSQ}$  balls must all be connected.



## **Package Dimensions**

Figure 5: 153-Ball WFBGA - 11.5mm x 13.0mm x 0.8mm (Package Code: EA)



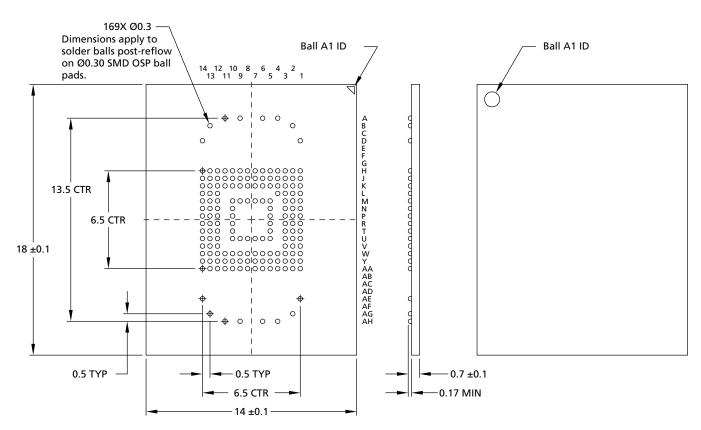


Note: 1. Dimensions are in millimeters.



Figure 6: 169-Ball WFBGA - 14.0mm x 18.00mm x 0.8mm (Package Code: EC)

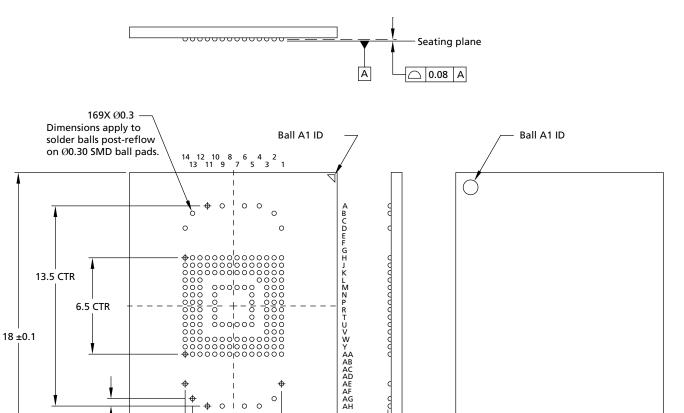




Note: 1. Dimensions are in millimeters.



Figure 7: 169-Ball VFBGA - 14.0mm x 18.00mm x 1.0mm (Package Code: ED)



-0.9 ±0.1

-0.17 MIN

Note: 1. Dimensions are in millimeters.

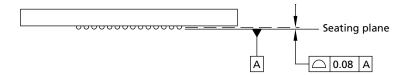
- 0.5 TYP

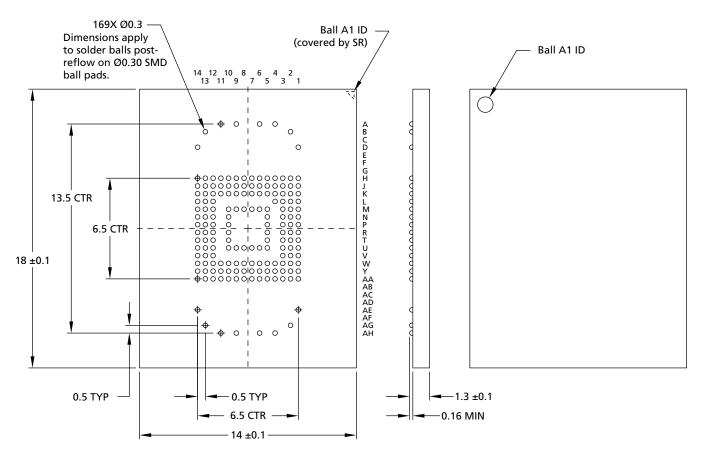
— 6.5 CTR -

0.5 TYP



Figure 8: 169-Ball LFBGA - 14.0mm x 18.00mm x 1.4mm (Package Code: DN)





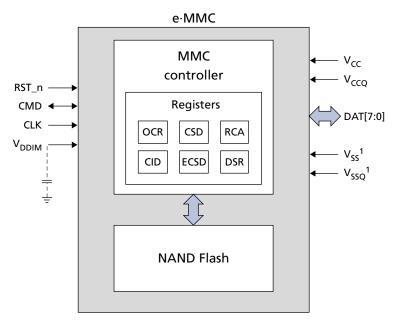
Note: 1. Dimensions are in millimeters.



#### 2GB, 4GB, 8GB, 16GB, 32GB, 64GB: e·MMC Architecture

#### **Architecture**

#### Figure 9: e-MMC Functional Block Diagram



Note: 1. V<sub>SS</sub> and V<sub>SSO</sub> are internally connected.

### **MMC Protocol Independent of NAND Flash Technology**

The MMC specification defines the communication protocol between a host and a device. The protocol is independent of the NAND Flash features included in the device. The device has an intelligent on-board controller that manages the MMC communication protocol.

The controller also handles block management functions such as logical block allocation and wear leveling. These management functions require complex algorithms and depend entirely on NAND Flash technology (generation or memory cell type).

The device handles these management functions internally, making them invisible to the host processor.

### **Defect and Error Management**

Micron *e*·MMC incorporates advanced technology for defect and error management. If a defective block is identified, the device completely replaces the defective block with one of the spare blocks. This process is invisible to the host and does not affect data space allocated for the user.

The device also includes a built-in error correction code (ECC) algorithm to ensure that data integrity is maintained.

To make the best use of these advanced technologies and ensure proper data loading and storage over the life of the device, the host must exercise the following precautions:

- Check the status after WRITE, READ, and ERASE operations.
- Avoid power-down during WRITE and ERASE operations.



## **CID Register**

The card identification (CID) register is 128 bits wide. It contains the device identification information used during the card identification phase as required by  $e \cdot \text{MMC}$  protocol. Each device is created with a unique identification number.

**Table 4: CID Register Field Parameters** 

| Name                  | Field | Width | CID Bits  | CID Value  |
|-----------------------|-------|-------|-----------|--|
| Manufacturer ID       | MID   | 8     | [127:120] | FEh  |
| Reserved              | _     | 6     | [119:114] | -  |
| Card/BGA              | CBX   | 2     | [113:112] | 01h  |
| OEM/application ID    | OID   | 8     | [111:104] | _  |
| Product name          | PNM   | 48    | [103:56]  | MMC02G<br>MMC04G<br>MMC08G<br>MMC16G<br>MMC32G<br>MMC64G |
| Product revision      | PRV   | 8     | [55:48]   | -  |
| Product serial number | PSN   | 32    | [47:16]   | _  |
| Manufacturing date    | MDT   | 8     | [15:8]    | _  |
| CRC7 checksum         | CRC   | 7     | [7:1]     | _  |
| Not used; always 1    | _     | 1     | 0         | _  |



## **CSD Register**

The card-specific data (CSD) register provides information about accessing the device contents. The CSD register defines the data format, error correction type, maximum data access time, and data transfer speed, as well as whether the DS register can be used. The programmable part of the register (entries marked with W or E in the following table) can be changed by the PROGRAM\_CSD (CMD27) command.

**Table 5: CSD Register Field Parameters** 

|  |                  |  | 2011 141 | Cell              | CSD       | CSD   |
|--|------------------|--|----------|-------------------|-----------|-------|
| Name   |                  | Field  | Width 2  | Type <sup>1</sup> | Bits      | Value |
| CSD structure                                      | CSD_STRUCTURE    |  |          | R                 | [127:126] | 03h   |
| System specification version                       | SPEC_VERS        |  | 4        | R                 | [125:122] | 4h    |
| Reserved <sup>2</sup>                              |                  | _  | 2        | TBD               | [121:120] | -     |
| Data read access time 1                            | TAAC             |  | 8        | R                 | [119:112] | 4Fh   |
| Data read access time 2 in CLK cycles (NSAC × 100) | NSAC             |  | 8        | R                 | [111:104] | 01h   |
| Maximum bus clock frequency                        | TRAN_SPEED       |  | 8        | R                 | [103:96]  | 32h   |
| Card command classes                               | ccc              |  | 12       | R                 | [95:84]   | 0F5h  |
| Maximum read data block                            | READ_BL_LEN      | 2GB  | 4        | R                 | [83:80]   | 0Ah   |
| length   |                  | 4GB,<br>4GB,<br>8GB,<br>16GB,<br>32GB,<br>64GB |          |                   |           | 09h   |
| Partial blocks for reads supported                 | READ_BL_PARTIAL  |  | 1        | R                 | 79        | 0h    |
| Write block misalignment                           | WRITE_BLK_MISALI | GN   | 1        | R                 | 78        | 0h    |
| Read block misalignment                            | READ_BLK_MISALIG | iN   | 77       | R                 | 77        | 0h    |
| DS register implemented                            | DSR_IMP          |  | 1        | R                 | 76        | 1h    |
| Reserved   |                  | _  | 2        | R                 | [75:74]   | _     |
| Device size  | C_SIZE           | 2GB  | 12       | R                 | [73:62]   | E4Fh  |
|  |                  | 4GB,<br>4GB,<br>8GB,<br>16GB,<br>32GB,         |          |                   |           | FFFh  |
| Maximum read current at V <sub>DD,min</sub>        | VDD_R_CURR_MIN   | •  | 3        | R                 | [61:59]   | 7h    |
| Maximum read current at V <sub>DD,max</sub>        | VDD_R_CURR_MAX   |  | 3        | R                 | [58:56]   | 7h    |
| Maximum write current at V <sub>DD,min</sub>       | VDD_W_CURR_MIN   |  | 3        | R                 | [55:53]   | 7h    |



#### **Table 5: CSD Register Field Parameters (Continued)**

| Name   | Field              |                        | Width | Cell<br>Type <sup>1</sup> | CSD<br>Bits | CSD<br>Value |
|--|--------------------|------------------------|-------|---------------------------|-------------|--------------|
| Maximum write current at V <sub>DD,max</sub> | VDD_W_CURR_MAX     |                        | 3     | R                         | [52:50]     | 7h           |
| Device size multiplier                       | C_SIZE_MULT        |                        | 3     | R                         | [49:47]     | 7h           |
| Erase group size                             | ERASE_GRP_SIZE     |                        | 5     | R                         | [46:42]     | 1Fh          |
| Erase group size multiplier                  | ERASE_GRP_MULT     | -                      | 5     | R                         | [41:37]     | 1Fh          |
| Write protect group size                     | WP_GRP_SIZE        | 2GB                    | 5     | R                         | [36:32]     | 03h          |
|  |                    | 4GB,<br>4GB            |       |                           |             | 07h          |
|  |                    | 8GB                    |       |                           |             | 0Fh          |
|  |                    | 16GB,<br>32GB,<br>64GB |       |                           |             | 1Fh          |
| Write protect group enable                   | WP_GRP_ENABLE      | -                      | 1     | R                         | 31          | 1h           |
| Manufacturer default ECC                     | DEFAULT_ECC        |                        | 2     | R                         | [30:29]     | 0h           |
| Write-speed factor                           | R2W_FACTOR         |                        | 3     | R                         | [28:26]     | 2h           |
| Maximum write data block length              | WRITE_BL_LEN       |                        | 4     | R                         | [25:22]     | 9h           |
| Partial blocks for writes supported          | WRITE_BL_PARTIA    | L                      | 1     | R                         | 21          | 0h           |
| Reserved                                     |                    | _                      | 4     | R                         | [20:17]     | _            |
| Content protection application               | CONTENT_PROT_A     | \PP                    | 1     | R                         | 16          | 0h           |
| File-format group                            | FILE_FORMAT_GR     | P                      | 1     | R/W                       | 15          | 0h           |
| Copy flag (OTP)                              | COPY               |                        | 1     | R/W                       | 14          | 0h           |
| Permanent write protection                   | PERM_WRITE_PROTECT |                        | 1     | R/W                       | 13          | 0h           |
| Temporary write protection                   | TMP_WRITE_PROTECT  |                        | 1     | R/W/E                     | 12          | 0h           |
| File format                                  | FILE_FORMAT        |                        | 2     | R/W                       | [11:10]     | 0h           |
| ECC  | ECC                |                        | 2     | R/W/E                     | [9:8]       | 0h           |
| CRC  | CRC                |                        | 7     | R/W/E                     | [7:1]       | _            |
| Not used; always 1                           |                    |                        | 1     | _                         | 0           | 1h           |

Notes: 1. R = Read-only

R/W = One-time programmable and readable

R/W/E = Multiple writable with value kept after a power cycle, assertion of the RST\_n signal, and any CMD0 reset, and readable

TBD = To be determined

2. Reserved bits should be read as 0.

3. The I<sub>PEAK, max</sub> driving capability can be modified according to the actual capacitive load on the e·MMC interface signals in the user application board, using CMD4.

| CMD4 Argument | Driving Capability (mA) |
|---------------|-------------------------|
| 0x01000000    | 4                       |
| 0x02000000    | 8                       |

### **Micron Confidential and Proprietary**



# 2GB, 4GB, 8GB, 16GB, 32GB, 64GB: e·MMC CSD Register

| 0x04000000 | 12 (default) |
|------------|--------------|
| 0x08000000 | 16           |
| 0x10000000 | 20           |
| 0x20000000 | 24           |
| 0x40000000 | 28           |
| 0x80000000 | 32           |



### **ECSD Register**

The 512-byte extended card-specific data (ECSD) register defines device properties and selected modes. The most significant 320 bytes are the properties segment. This segment defines device capabilities and cannot be modified by the host. The lower 192 bytes are the modes segment. The modes segment defines the configuration in which the device is working. The host can change the properties of modes segments using the SWITCH command.

**Table 6: ECSD Register Field Parameters** 

| Name  |                               | Field               | Size<br>(Bytes) | Cell<br>Type <sup>1</sup> | ECSD<br>Bytes | ECSD<br>Value |
|---|-------------------------------|---------------------|-----------------|---------------------------|---------------|---------------|
| Properties Segment  |                               |                     | <u> </u>        |                           |               |               |
| Reserved <sup>2</sup>   |                               | _                   | 7               | _                         | [511:505]     | _             |
| Supported command sets  | S_CMD_SET                     |                     | 1               | R                         | 504           | 1h            |
| HPI features  | HPI_FEATURES                  |                     | 1               | R                         | 503           | 3h            |
| Background operations support                                   | BKOPS_SUPPORT                 |                     | 1               | R                         | 502           | 1h            |
| Reserved  |                               | _                   | 255             | _                         | [501:247]     | _             |
| Background operations status                                    | BKOPS_STATUS                  |                     | 1               | R                         | 246           | 0h            |
| Number of correctly program-<br>ned sectors                     | CORRECTLY_PRG_<br>SECTORS_NUM |                     | 4               | R                         | [245:242]     | -             |
| irst initialization time after                                  | INI_TIMEOUT_PA                | 2GB                 | 1               | R                         | 241           | 7Ah           |
| partitioning  |                               | 4GB                 |                 |                           |               | F6h           |
| first CMD1 to device ready)                                     |                               | 4GB                 |                 |                           |               | 7Ah           |
|   |                               | 8GB,<br>16GB        |                 |                           |               | F6h           |
|   |                               | 32GB,<br>64GB       |                 |                           |               | FFh           |
| Reserved  |                               | _                   | 1               | -                         | 240           | _             |
| Power class for 52 MHz, DDR at 8.6V <sup>3</sup>                | PWR_CL_DDR_52_                | 360                 | 1               | R                         | 239           | 0h            |
| Power class for 52 MHz, DDR at 1.95V <sup>3</sup>               | PWR_CL_DDR_52_                | 195                 | 1               | R                         | 238           | 0h            |
| Reserved  |                               | _                   | 2               | _                         | [237:236]     | _             |
| Minimum write performance<br>for 8-bit at 52 MHz in DDR<br>mode | MIN_PERF_DDR_W                | MIN_PERF_DDR_W_8_52 |                 | R                         | 235           | 0h            |
| Minimum read performance for<br>3-bit at 52 MHz in DDR mode     | MIN_PERF_DDR_R                | _8_52               | 1               | R                         | 234           | 0h            |
| Reserved  |                               | _                   | 1               | _                         | 233           | _             |



| Name                    |                | Field                      | Size<br>(Bytes) | Cell<br>Type <sup>1</sup> | ECSD<br>Bytes | ECSD<br>Value |
|-------------------------|----------------|----------------------------|-----------------|---------------------------|---------------|---------------|
| TRIM multiplier         | TRIM_MULT      | 2GB<br>4GB,<br>4GB,<br>8GB | 1               | R                         | 232           | 06h           |
|                         |                | 16GB,<br>32GB,<br>64GB     |                 |                           |               | 0Fh           |
| Secure feature support  | SEC_FEATURE_SU | PPORT                      | 1               | R                         | 231           | 15h           |
| SECURE ERASE multiplier | SEC_ERASE_MULT | 2GB<br>4GB,<br>4GB,<br>8GB | 1               | R                         | 230           | 02h           |
|                         |                | 16GB,<br>32GB,<br>64GB     |                 |                           |               | 06h           |
| SECURE TRIM multiplier  | SEC_TRIM_MULT  | 2GB<br>4GB,<br>4GB,<br>8GB | 1               | R                         | 229           | 03h           |
|                         |                | 16GB,<br>32GB,<br>64GB     |                 |                           |               | 09h           |
| Boot information        | BOOT_INFO      | •                          | 1               | R                         | 228           | 7h            |
| Reserved                |                | _                          | 1               | _                         | 227           | _             |
| Boot partition size     | BOOT_SIZE_MULT | 2GB,<br>4GB                | 1               | R                         | 226           | 08h           |
|                         |                | 4GB,<br>8GB                |                 |                           |               | 10h           |
|                         |                | 16GB                       |                 |                           |               | 20h           |
|                         |                | 32GB,<br>64GB              |                 |                           |               | 40h           |
| Access size             | ACC_SIZE       | 2GB,<br>4GB                | 1               | R                         | 225           | 05h           |
|                         |                | 4GB,<br>8GB                |                 |                           |               | 06h           |
|                         |                | 16GB,<br>32GB,<br>64GB     |                 |                           |               | 07h           |



|   |                 |                        | Size    | Cell              | ECSD      | ECSD      |
|---|-----------------|------------------------|---------|-------------------|-----------|-----------|
| Name  |                 | Field                  | (Bytes) | Type <sup>1</sup> | Bytes     | Value     |
| High-capacity erase unit size   | HC_ERASE_GRP_S  | 2GB                    | 1       | R                 | 224       | 00h       |
|   | IZE             | 4GB                    |         |                   |           | 04h       |
|   |                 | 4GB,                   |         |                   |           | 08h       |
|   |                 | 8GB                    |         |                   |           |           |
|   |                 | 16GB,<br>32GB,<br>64GB |         |                   |           | 10h       |
| High-capacity erase timeout   | ERASE_TIMEOUT_  | MULT                   | 1       | R                 | 223       | 01h       |
| Reliable write-sector count   | REL_WR_SEC_C    |                        | 1       | R                 | 222       | 01h       |
| High-capacity write protect   | HC_WP_GRP_SIZE  | 2GB                    | 1       | R                 | 221       | 00h       |
| group size  |                 | 4GB                    |         |                   |           | 02h       |
|   |                 | 4GB                    |         |                   |           | 01h       |
|   |                 | 8GB,<br>16GB           |         |                   |           | 02h       |
|   |                 | 32GB                   |         |                   |           | 04h       |
|   |                 | 64GB                   |         |                   |           | 08h       |
| Sleep current (V <sub>CC</sub> )  | S_C_VCC         |                        | 1       | R                 | 220       | 08h       |
| Sleep current (V <sub>CCO</sub> )                                       | s_c_vccq        |                        | 1       | R                 | 219       | 08h       |
| Reserved  |                 | _                      | 1       | _                 | 218       | -         |
| Sleep/awake timeout   | S_A_TIMEOUT     |                        | 1       | R                 | 217       | 10h       |
| Reserved  |                 | _                      | 1       | _                 | 216       | _         |
| Sector count  | SEC_COUNT       | 2GB                    | 4       | R                 | [215:212] | 00000000h |
|   |                 | 4GB                    |         |                   |           | 00750000h |
|   |                 | 4GB                    |         |                   |           | 00728000h |
|   |                 | 8GB                    |         |                   |           | 00EA0000h |
|   |                 | 16GB                   |         |                   |           | 01D40000h |
|   |                 | 32GB                   |         |                   |           | 03B20000h |
|   |                 | 64GB                   |         |                   |           | 07700000h |
| Reserved  |                 | _                      | 1       | _                 | 211       | _         |
| Minimum write performance for 8-bit at 52 MHz                           | MIN_PERF_W_8_52 | 2                      | 1       | R                 | 210       | 08h       |
| Minimum read performance for<br>8-bit at 52 MHz                         | MIN_PERF_R_8_52 |                        | 1       | R                 | 209       | 08h       |
| Minimum write performance<br>for 8-bit at 26 MHz and 4-bit at<br>52 MHz | MIN_PERF_W_8_26 | 6_4_52                 | 1       | R                 | 208       | 08h       |
| Minimum read performance for<br>8-bit at 26 MHz and 4-bit at 52<br>MHz  | MIN_PERF_R_8_26 | _4_52                  | 1       | R                 | 207       | 08h       |



|   |                       | Size    | Cell                        | ECSD | ECSD  |  |  |
|---|-----------------------|---------|-----------------------------|------|-------|--|--|
| Name  | Field                 | (Bytes) | es) Type <sup>1</sup> Bytes |      | Value |  |  |
| Minimum write performance for 4-bit at 26 MHz   | MIN_PERF_W_4_26       | 1       | R                           | 206  | 08h   |  |  |
| Minimum read performance for<br>4-bit at 26 MHz | MIN_PERF_R_4_26       | 1       | R                           | 205  | 08h   |  |  |
| Reserved  | -                     | 1       | _                           | 204  | -     |  |  |
| Power class for 26 MHz at 3.6V <sup>3</sup>     | PWR_CL_26_360         | 1       | R                           | 203  | 00h   |  |  |
| Power class for 52 MHz at 3.6V <sup>3</sup>     | PWR_CL_52_360         | 1       | R                           | 202  | 00h   |  |  |
| Power class for 26 MHz at 1.95V <sup>3</sup>    | PWR_CL_26_195         | 1       | R                           | 201  | 00h   |  |  |
| Power class for 52 MHz at 1.95V <sup>3</sup>    | PWR_CL_52_195         | 1       | R                           | 200  | 00h   |  |  |
| Partition switching timing                      | PARTITION_SWITCH_TIME | 1       | R                           | 199  | 1h    |  |  |
| Out-of-interrupt busy timing                    | OUT_OF_INTERRUPT_TIME | 1       | R                           | 198  | 02h   |  |  |
| Reserved  | -                     | 1       | _                           | 197  | -     |  |  |
| Card type                                       | CARD_TYPE             | 1       | R                           | 196  | 07h   |  |  |
| Reserved  | -                     | 1       | _                           | 195  | -     |  |  |
| CSD structure version                           | CSD_STRUCTURE         | 1       | R                           | 194  | 2h    |  |  |
| Reserved  | -                     | 1       | _                           | 193  | -     |  |  |
| Extended CSD revision                           | EXT_CSD_REV           | 1       | R                           | 192  | 5h    |  |  |
| Modes Segment                                   |                       | •       |                             |      |       |  |  |
| Command set                                     | CMD_SET               | 1       | R/W/E_P                     | 191  | 0h    |  |  |
| Reserved  | -                     | 1       | _                           | 190  | _     |  |  |
| Command set revision                            | CMD_SET_REV           | 1       | R                           | 189  | 0h    |  |  |
| Reserved  | -                     | 1       | _                           | 188  | _     |  |  |
| Power class                                     | POWER_CLASS           | 1       | R/W/E_P                     | 187  | 0h    |  |  |
| Reserved  | -                     | 1       | _                           | 186  | _     |  |  |
| High-speed interface timing                     | HS_TIMING             | 1       | R/W/E_P                     | 185  | 0h    |  |  |
| Reserved  | -                     | 1       | _                           | 184  | _     |  |  |
| Bus width mode                                  | BUS_WIDTH             | 1       | W/E_P                       | 183  | 0h    |  |  |
| Reserved  | -                     | 1       | -                           | 182  | _     |  |  |
| Erased memory content                           | ERASED_MEM_CONT       | 1       | R                           | 181  | 0h    |  |  |
| Reserved  | -                     | 1       | _                           | 180  | _     |  |  |
| Partition configuration                         | PARTITION_CONFIG      | 1       | R/W/E,<br>R/W/E_P           | 179  | 0h    |  |  |
| Boot configuration protection                   | BOOT_CONFIG_PROT      | 1       | R/W,<br>R/W/C_P             | 178  | 0h    |  |  |
| Boot bus width                                  | BOOT_BUS_WIDTH        | 1       | R/W/E                       | 177  | 0h    |  |  |
| Reserved  | -                     | 1       | _                           | 176  | _     |  |  |



|   |                             |              | Size    |                             |           | ECSD             |  |
|---|-----------------------------|--------------|---------|-----------------------------|-----------|------------------|--|
| Name  |                             | Field        | (Bytes) | Type <sup>1</sup>           | Bytes     | Value            |  |
| High-density erase group defi-<br>nition        | ERASE_GROUP_D               | 1            | R/W/E_P | 175                         | 00h       |                  |  |
| Reserved  | _                           |              | 1       | _                           | 174       | _                |  |
| Boot area write protection register             | BOOT_WP                     |              | 1       | R/W,<br>R/W/C_P             | 173       | 0h               |  |
| Reserved  |                             | _            | 1       | _                           | 172       | _                |  |
| User write protection register                  | USER_WP                     |              | 1       | R/W,<br>R/W/C_P,<br>R/W/E_P | 171       | 0h               |  |
| Reserved  |                             | _            | 1       | _                           | 170       | -                |  |
| Firmware configuration                          | FW_CONFIG                   |              | 1       | R/W                         | 169       | 0h               |  |
| RPMB size                                       | RPMB_SIZE_MULT              | •            | 1       | R                           | 168       | 1h               |  |
| Write reliability setting register <sup>3</sup> | WR_REL_SET                  |              | 1       | R/W                         | 167       | 00h <sup>4</sup> |  |
| Write reliability parameter register            | WR_REL_PARAM                |              | 1       | R                           | 166       | 05h              |  |
| Reserved  | _                           |              | 1       | _                           | 165       | _                |  |
| Manually start background operations            | BKOPS_START                 |              | 1       | W/E_P                       | 164       | -                |  |
| Enable background operations handshake          | BKOPS_EN                    |              | 1       | R/W                         | 163       | 0h               |  |
| Hardware reset function                         | RST_n_FUNCTION              |              | 1       | R/W                         | 162       | 0h               |  |
| HPI management                                  | HPI_MGMT                    |              | 1       | R/W/E_P                     | 161       | 0h               |  |
| Partitioning support                            | PARTITIONING_SU             | JPPORT       | 1       | R                           | 160       | 3h               |  |
| Maximum enhanced area size                      | MAX_ENH_SIZE_               | 2GB          | 3       | R                           | [159:157] | 0001CAh          |  |
|   | MULT                        | 4GB          |         |                             |           | 0001D4h          |  |
|   |                             | 4GB          |         |                             |           | 0001CAh          |  |
|   |                             | 8GB,<br>16GB |         |                             |           | 0001D4h          |  |
|   |                             | 32GB         |         |                             |           | 0001D9h          |  |
|   |                             | 64GB         |         |                             |           | 0001DCh          |  |
| Partitions attribute                            | PARTITIONS_ATTR             | RIBUTE       | 1       | R/W                         | 156       | 0h               |  |
| Partitioning setting                            | PARTITION_SETTING_COMPLETED |              | 1       | R/W                         | 155       | 0h               |  |
| General-purpose partition size                  | GP_SIZE_MULT                |              | 12      | R/W                         | [154:143] | 0h               |  |
| Enhanced user data area size                    | ENH_SIZE_MULT               |              | 3       | R/W                         | [142:140] | 0h               |  |
| Enhanced user data start address                | ENH_START_ADDR              |              | 4       | R/W                         | [139:136] | 0h               |  |
| Reserved  | _                           |              | 1       | _                           | 135       | _                |  |
| Bad block management mode                       | SEC_BAD_BLK_M               | GMNT         | 1       | R/W                         | 134       | 0h               |  |



#### **Table 6: ECSD Register Field Parameters (Continued)**

| Name     | Field | Size<br>(Bytes) | Cell<br>Type <sup>1</sup> | ECSD<br>Bytes | ECSD<br>Value |
|----------|-------|-----------------|---------------------------|---------------|---------------|
| Reserved | -     | 134             | _                         | [133:0]       | _             |

Notes: 1. R = Read-only

R/W = One-time programmable and readable

R/W/E = Multiple writable with the value kept after a power cycle, assertion of the RST\_n signal, and any CMD0 reset, and readable

R/W/C\_P = Writable after the value is cleared by a power cycle and assertion of the RST\_n signal (the value not cleared by CMD0 reset) and readable

R/W/E\_P = Multiple writable with the value reset after a power cycle, assertion of the RST\_n signal, and any CMD0 reset, and readable

W/E\_P = Multiple writable with the value reset after power cycle, assertion of the RST\_n signal, and any CMD0 reset, and not readable

TBD = To be determined

- 2. Reserved bits should be read as 0.
- 3. Micron has tested power failure under best application knowledge conditions with positive results. Customers may request a dedicated test for their specific application condition.
- 4. Can be set to 1Fh to enable reliability settings. This byte is one-time programmable.
- 5. The first showing of 4GB refers to the 1-channel device, while the second showing of 4GB refers to the 2-channel device.



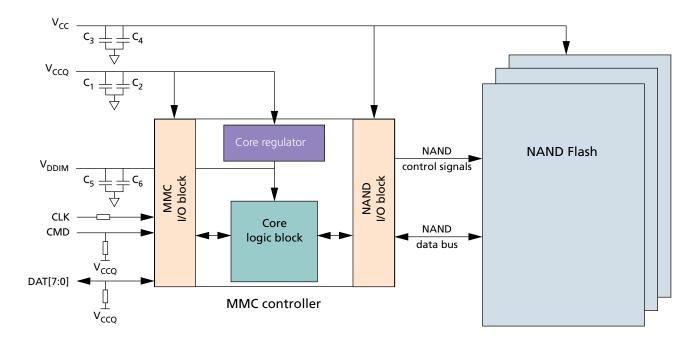
## 2GB, 4GB, 8GB, 16GB, 32GB, 64GB: e·MMC DC Electrical Specifications – Device Power

## **DC Electrical Specifications – Device Power**

The device current consumption for various device configurations is defined in the power class fields of the ECSD register.

 $V_{CC}$  is used for the NAND Flash device and its interface voltage;  $V_{CCQ}$  is used for the controller and the e-MMC interface voltage.

**Figure 10: Device Power Diagram** 



**Table 7: Power Domains** 

| Parameter      | Symbol            | Comments  |
|----------------|-------------------|---|
| Host interface | V <sub>CCQ</sub>  | High voltage range = 3.3V (nominal)                                   |
|                |                   | Low voltage range = 1.8V (nominal)                                    |
| Memory         | V <sub>CC</sub>   | High voltage range = 3.3V (nominal)                                   |
| Internal       | V <sub>DDIM</sub> | The internal regulator connection to an external decoupling capacitor |



### 2GB, 4GB, 8GB, 16GB, 32GB, 64GB: e·MMC **DC Electrical Specifications – Device Power**

**Table 8: Capacitor and Resistance Specifications** 

| Parameter                                       | Symbol  | Min | Max  | Тур  | Units | Notes |
|---|---------|-----|------|------|-------|-------|
| Pull-up resistance: CMD                         | R_CMD   | 4.7 | 50   | 10   | kΩ    | 1     |
| Pull-up resistance: DAT[7:0]                    | R_DAT   | 10  | 50   | 50   | kΩ    | 1     |
| Pull-up resistance: RST_n                       | R_RST_n | 4.7 | 50   | 50   | kΩ    | 2     |
| CLK/CMD/DAT[7:0] impedance                      |         | 45  | 55   | 50   | Ω     | 3     |
| Serial resistance on CLK                        | SR_CLK  | 0   | 47   | 22   | Ω     |       |
| V <sub>CCQ</sub> capacitor                      | C1      | 2.2 | 4.7  | 2.2  | μF    | 4     |
|   | C2      | 0.1 | 0.22 | 0.1  |       |       |
| V <sub>CC</sub> capacitor (≤8GB)                | C3      | 2.2 | 4.7  | 2.2  | μF    | 5     |
|   | C4      | 0.1 | 0.22 | 0.1  |       |       |
| V <sub>CC</sub> capacitor (>8GB)                | C3      | 2.2 | 4.7  | 4.7  | μF    | 5     |
|   | C4      | 0.1 | 0.22 | 0.22 |       |       |
| V <sub>DDIM</sub> capacitor (C <sub>reg</sub> ) | C5      | 1   | 4.7  | 1    | μF    | 6     |
|   | C6      | 0.1 | 0.1  | 0.1  |       |       |

- Notes: 1. Used to prevent bus floating.
  - 2. If host does not use H/W RESET (RST\_n), pull-up resistance is not needed on RST\_n line  $(Extended_CSD[162] = 00h).$
  - 3. Impedance match.
  - 4. The coupling capacitor should be connected with  $V_{\text{CCQ}}$  and  $V_{\text{SSQ}}$  as closely as possible.
  - 5. The coupling capacitor should be connected with  $V_{CC}$  and  $V_{SS}$  as closely as possible.
  - 6. The coupling capacitor should be connected with  $V_{\text{DDIM}}$  and  $V_{\text{SS}}$  as closely as possible.



### 2GB, 4GB, 8GB, 16GB, 32GB, 64GB: e·MMC Revision History

### **Revision History**

Rev. B - 09/13

- To Production status
- Added channel note to ECSD Register

Rev. A - 03/13

· Initial release

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This data sheet contains minimum and maximum limits specified over the power supply and temperature range set forth herein. Although considered final, these specifications are subject to change, as further product development and data characterization sometimes occur.